

# MBR20S100CT Schottky Barrier Rectifier

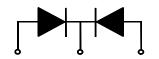
### **Features**

- · Low forward voltage drop
- · High frequency properties and switching speed
- · Guard ring for over-voltage protection

### **Applications**

- · Switched mode power supply
- · Freewheeling diodes





1. Anode 2. Cathode 3. Anode

### Absolute Maximum Ratings T<sub>a</sub> = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>RRM</sub>	Maximum Repetitive Reverse Voltage	100	V
$V_R$	Maximum DC Reverse Voltage	100	V
I <sub>F(AV)</sub>	Average Rectified Forward Current @T <sub>C</sub> = 135°C	20	Α
I <sub>FSM</sub>	Non-Repetitive Peak Surge Current (per diode) 60Hz Single Half-Sine Wave	200	А
T <sub>J</sub> , T <sub>STG</sub>	Operating Junction and Storage Temperature	-65 to +150	°C

### **Thermal Characteristics**

Symbol	Parameter	Value	Units
$R_{\theta JC}$	Maximum Thermal Resistance, Junction to Case (per diode)	1.54	°C/W

## Electrical Characteristics T<sub>C</sub> = 25°C unless otherwise noted

Symbol	nbol Parameter		Parameter Value		Units
V <sub>FM*</sub>	$\label{eq:maximum Instantaneous Forward Voltage} $$I_F = 10A$$$I_F = 10A$$$I_F = 20A$$$I_F = 20A$$$$	$T_{C} = 25^{\circ}C$ $T_{C} = 125^{\circ}C$ $T_{C} = 25^{\circ}C$ $T_{C} = 25^{\circ}C$	0.70 0.95 0.85	V V V	
I <sub>RM*</sub>	Maximum Instantaneous Reverse Current @ rated V <sub>R</sub>	T <sub>C</sub> = 25°C T <sub>C</sub> = 125°C	0.1 20	mA mA	

<sup>\*</sup> Pulse Test: Width =  $300\mu s$ , Duty Cycle = 2%

## **Typical Performance Characteristics**

Figure 1. Typical Forward Voltage Characteristics (per diode)

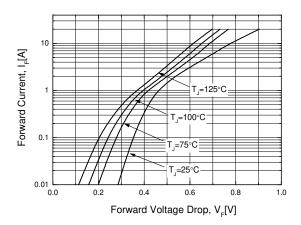


Figure 2. Typical Reverse Current vs. Reverse Voltage (per diode)

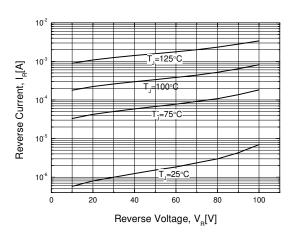
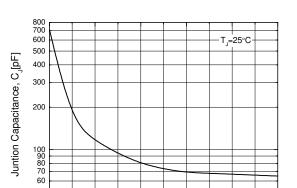
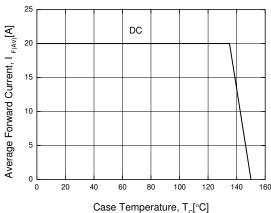


Figure 3. Typical Junction Capacitance (per diode)

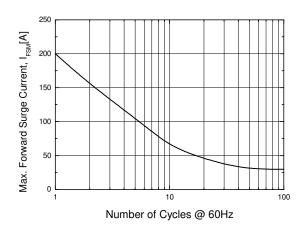


MBR20S100CT Rev. A

Figure 4. Forward Current Derating Curve



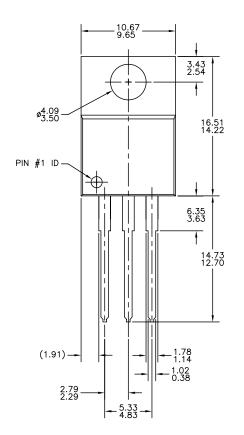
Reverse Voltage,  $V_R[V]$  Case Temp Figure 5. Non-Repetive Surge Current (per diode)

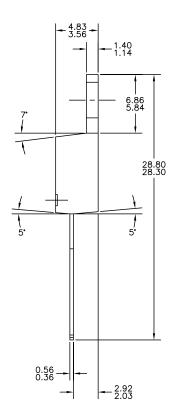


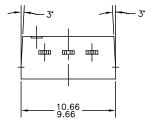
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## **Mechanical Dimensions**

TO-220







NOTES: UNLESS OTHERWISE SPECIFIED

- STANDARD LEAD FINISH: 200 MICROINCHES / 5.08 MICROMETERS MIN. LEAD/TIN 15/85 ON COPPER.
- REFERENCE JEDEC, TO-220, ISSUE J, VARIATION AB, DATED MARCH 24, 1987. ALL DIMENSIONS ARE IN MILLIMETERS. DIMENSIONING AND TOLERANCING PER ANSI Y14.5 1973

Dimensions in Millimeters

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